## NSN 5961-01-132-8067

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-132-8067 **Inclosure Material:** Metal **Overall Length:** 0.499 inches **End Application:** Ef111acicpane 26512 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and radiation tolerant **Thread Size:** 6.0 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 60.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Iso m **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0